

LB1287,1288

Darlington Transistor Array

These ICs have circuit configuration of 5-unit Darlington transistor array consisting of NPN transistors and are capable of causing small input current to provide large current drive. They can be advantageously incorporated in equipment because the specially designed 14-pin DIP makes such equipment more compact.

Features

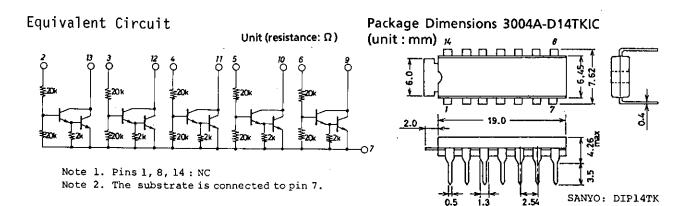
- Large maximum drive current. 400mALarge allowable power dissipation. 1.15W
- . Wide range of operating supply voltage. LB1287 5 to 30V, LB1288 5 to 20V
- . Wide range of operating temperature. -20 to +80°C
 . Large current-amplification factor. 2000 or more

Applications

- . Various types of driver(relay, solenoid, motor, etc.).
- . Display segment or digit driver (LED, lamp).
- . Interface to MOS or bipolar logic IC.
- . Power amplification of pulse (fan-out extension, etc.).

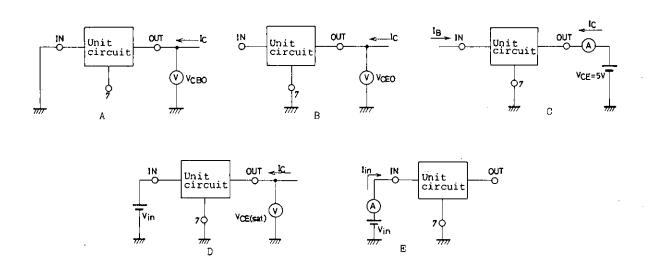
Absolute Maximum Ratings at Ta=	=25°C			unit
Collector-Base Voltage	VCBO	[LB1287]	30	V
	VCBO	[LB1287]		•
0-11			20	V
Collector-Emitter Voltage	v_{CEO}	[LB1287]	-0.7 to +30	V
		[LB1288]	-0.7 to $+20$	V
Allowable Power Dissipation	P_{d} max		1.15	W
Input Voltage	Vin	Per unit	-0.7 to +45	V
Collector Current	I_{C}	Per unit	500	mΑ
Junction Temperature	Тj		125	°C
Operating Temperature	Topr		-20 to $+80$	°C
Storage Temperature	${ m Tstq}$		-40 to +125	°C
de la combinación de				

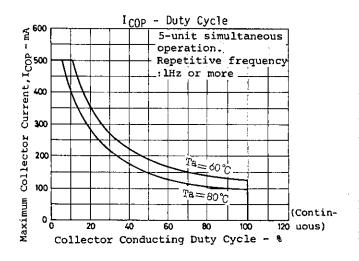
*: The substrate is connected to emitter.

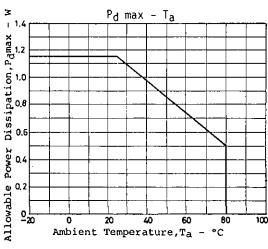


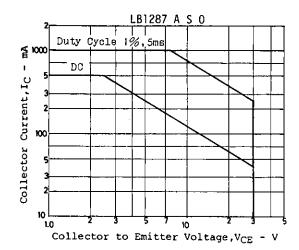
Allowable Operating Conditio	ns at T	a=25°C	·				unit	:
Supply Voltage V _{CC}	[LB	1287]			5 to	30	V	
	[LB	1288]			5 to	20	V	
Collector Current Icop(1) Tur	ning ON 5 u	nits simult	aneously,	2	80	mΑ	
_	Ta=	80°C,20% d	uty					
I _{cop} (2) Turi	ning ON 5 u	nits simult	aneously,]	_50	mΑ	
-		80°C 50% d	uty					
I _{cop} (3) Turi	ning ON 5 u	nits simult	aneously,]	.00	mΑ	
		80°C,DC						
Electrical Characteristics a	t Ta=25	°C		Test circuit	min	typ	max	unit
Collector-Base Voltage	v_{CBO}	I _C =50µA	[LB1287]	A	30			V
			[LB1288]	A	20			V
Collector-Emitter Voltage	v_{CEO}	I _C =100µA	[LB1287]	В	30			v
		·	[LB1288]	В	20			v
DC Current Gain	${ m h_{FE}}$	$v_{CE}=5v,I_{C}$	=200mA	C	2000			
Collector-Emitter Satura-	VCE(sat)	$v_{in}=12V,I$	C=400mA	D			2.3	V
tion Voltage		$v_{in}=9.5v$,	I _C ≔300mA	D			1.8	v
		$v_{in}=7.0v$,	I _C =200mA	D			1.4	V
Input Current	I_{in}	v_{in} =17 v	_	E		0.8		mA

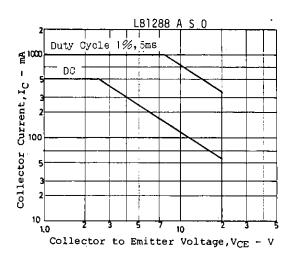
Test Circuit











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